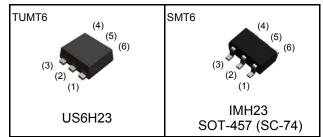
# US6H23 / IMH23

NPN 600mA 20V Digital Transistors (Bias Resistor Built-in Transistors) For Muting.

Parameter	Tr1 and Tr2
$V_{\sf CEO}$	20V
$V_{EBO}$	12V
I <sub>C</sub>	600mA
$R_1$	4.7kΩ

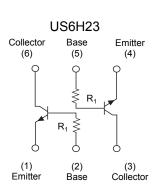
#### Outline

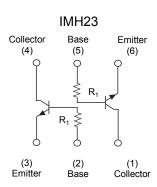


#### Features

- 1) Built-In Biasing Resistors
- 2) Two DTC643T chips in one package.
- 3) Low saturation voltage, typically  $V_{CE(sat)}$  =40mV at  $I_C$  /  $I_B$ =50mA / 2.5mA, makes these transistors ideal for muting circuits.
- 4) These transistors can be used at high current levels,  $I_{\text{C}}$ =600mA.
- 5) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 6) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 7) Lead Free/RoHS Compliant.

#### •Inner circuit





## Application

Muting circuit

## Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
US6H23	TUMT6	2021	TN	180	8	3,000	H23
IMH23	SMT6	2928	T110	180	8	3,000	H23

# ●Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter		Symbol	Values	Unit
Collector-base voltage		$V_{CBO}$	20	V
Collector-emitter voltage		$V_{CEO}$	20	V
Emitter-base voltage		$V_{EBO}$	12	V
Collector current		I <sub>C</sub>	600	mA
		I <sub>CP</sub> *1	1	Α
Power dissipation US6H23 IMH23		P <sub>D</sub> *2	1(TOTAL) *3	W
		P <sub>D</sub> *4	300(TOTAL) *5	mW
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	−55 to +150	°C

## ●Electrical characteristics (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = 50μA	20	-	-	V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1mA	20	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 50μA	12	-	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 20V	-	-	0.5	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 12V	ı	1	0.5	μΑ
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C / I_B = 50 \text{mA} / 2.5 \text{mA}$	ı	40	150	mV
DC current gain	h <sub>FE</sub>	$V_{CE}$ = 5V , $I_{C}$ = 50mA	820	-	2700	-
Input resistance	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ
Transition frequency	$f_{T}^{*6}$	V <sub>CE</sub> = 10V, I <sub>E</sub> = -50mA f = 100MHz	-	150	-	MHz
Output ON Resistance	R <sub>on</sub>	$V_1 = 5V$ $R_L = 1k\Omega, f = 1kHz$	-	0.55	-	Ω

<sup>\*1</sup> P<sub>W</sub>=10ms, Single pulse

<sup>\*2</sup> Mounted on a ceramic board

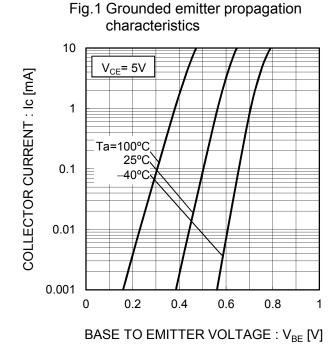
<sup>\*3 700</sup>mW per element mounted on ceramic board.

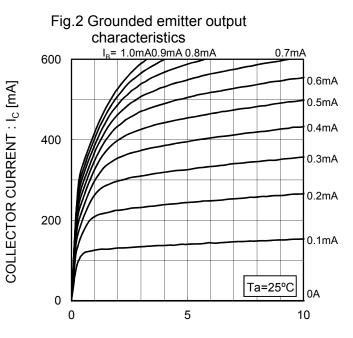
<sup>\*4</sup> Each terminal mounted on a reference footprint

<sup>\*5 200</sup>mW per element must not be exceeded.

<sup>\*6</sup> Characteristics of built-in transistor

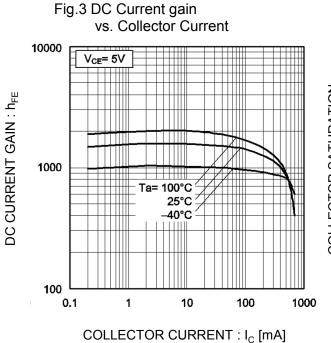
## ●Electrical characteristic curves(Ta = 25°C)

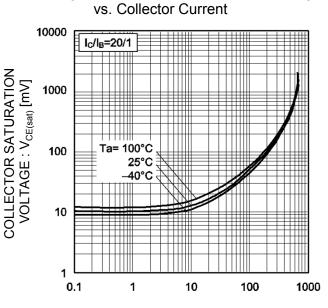




COLLECTOR TO EMITTER VOLTAGE :  $V_{CE}[V]$ 

Fig.4 Collector-emitter saturation voltage





COLLECTOR CURRENT :  $I_C$  [mA]

0.1

## ●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output ON resistance

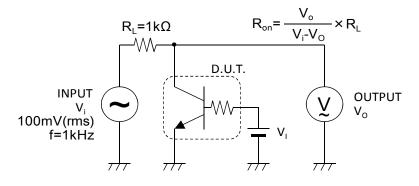
INPUT VOLTAGE: V<sub>I</sub> [V]

10

100

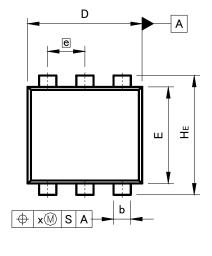
Fig.6 Ron measurement circuit.

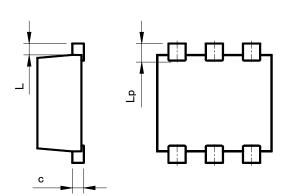
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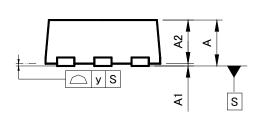


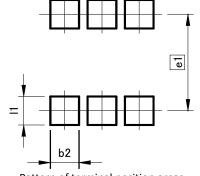
# ●Dimensions (Unit : mm)











Pattern of terminal position areas [Not a recommended pattern of soldering pads]

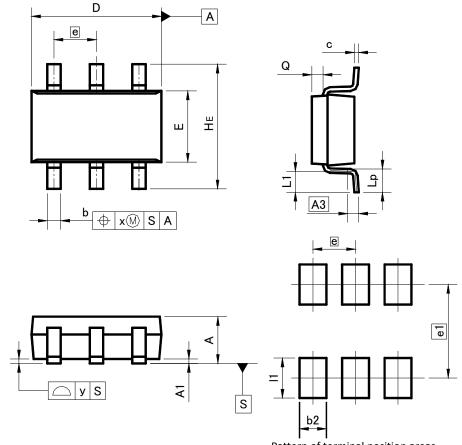
DIM MILIMETERS		ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	-	0.85	ı	0.033
A1	0.00	0.10	0.000	0.004
A2	0.72	0.82	0.028	0.032
b	0.25	0.40	0.010	0.016
С	0.12	0.22	0.005	0.009
D	1.90	2.10	0.075	0.083
Е	1.60	1.80	0.063	0.071
е	0.0	65	0.0	26
HE	2.00	2.20	0.079	0.087
L	0.3	20	0.0	08
Lp	_	0.40		0.016
х	_	0.10		0.004
У	_	0.10	_	0.004

DIM MILIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX
b2	1	0.50	1	0.020
e1	1.70		0.0	67
l1	_	0.50	_	0.020

Dimension in mm / inches

# ●Dimensions (Unit : mm)





Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM MILI		ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.5	25	0.0	10
b	0.25	0.40	0.010	0.016
С	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
Е	1.50	1.80	0.059	0.071
е	0.9	0.95		37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
х	_	0.20	_	0.008
У	_	0.10	_	0.004

MILIMETERS MILIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX
b2		0.60	_	0.024
e1	2.	10	0.0	083
l1	_	0.90	_	0.035

Dimension in mm / inches

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